Product data sheet

1. General description

PNP low V_{CEsat} transistor in a SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package.

NPN complement: PBSS8110T

2. Features and benefits

- Low collector-emitter saturation voltage V_{CEsat} and corresponding low RCEsat
- High collector current capability
- · High collector current gain
- · Improved efficiency due to reduced heat generation

3. Applications

- Major application segments
 - · Automotive 42 V power
 - · Telecom infrastructure
 - Industrial
- DC/DC converters
- Peripheral drivers
 - Driver in low supply voltage applications (e.g. lamps and LEDs)
 - Inductive load driver (e.g. relays, buzzers and motors)

4. Quick reference data

Table 1. Quick reference data

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|--------------------|---|---|-----|-----|------|------|
| V _{CEO} | collector-emitter voltage | open base | - | - | -100 | V |
| I _C | collector current | | - | - | -1 | Α |
| I _{CM} | peak collector current | limited by T _{j(max)} | - | - | -3 | Α |
| R _{CEsat} | collector-emitter saturation resistance | I_C = -1 A; I_B = -100 mA; pulsed; $t_p \le$ 300 μs; $\delta \le$ 0.02; T_{amb} = 25 °C | - | 170 | 320 | mΩ |



100 V, 1 A PNP low VCEsat transistor

5. Pinning information

Table 2. Pinning information

| Pin | Symbol | Description | Simplified outline | Graphic symbol |
|-----|--------|-------------|--------------------|---------------------|
| 1 | В | base | 3 | |
| 2 | Е | emitter | | C |
| 3 | С | collector | | В |
| | | | 1 2 | E sym132 |
| | | | SOT23 | |

6. Ordering information

Table 3. Ordering information

| Type number | Package | | |
|-------------|---------|--|---------|
| | Name | Description | Version |
| PBSS9110T | SOT23 | plastic, surface-mounted package; 3 terminals; 1.9 mm pitch; 2.9 mm x 1.3 mm x 1 mm body | SOT23 |

7. Marking

Table 4. Marking codes

| Type number | Marking code[1] |
|-------------|-----------------|
| PBSS9110T | %U7 |

[1] % = placeholder for manufacturing site code

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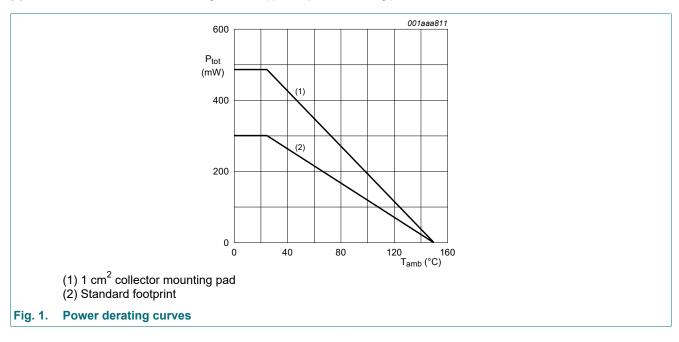
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | | Min | Max | Unit |
|------------------|---------------------------|--------------------------------|-----|-----|------|------|
| V _{CBO} | collector-base voltage | open emitter | | - | -120 | V |
| V _{CEO} | collector-emitter voltage | open base | | - | -100 | V |
| V _{EBO} | emitter-base voltage | open collector | | - | -5 | V |
| Ic | collector current | | | - | -1 | Α |
| I _{CM} | peak collector current | limited by T _{j(max)} | | - | -3 | Α |
| I _B | base current | | | - | -300 | mA |
| P _{tot} | total power dissipation | T _{amb} ≤ 25 °C | [1] | - | 300 | mW |
| | | | [2] | - | 480 | mW |
| Tj | junction temperature | | | - | 150 | °C |
| T _{amb} | ambient temperature | | | -65 | 150 | °C |
| T _{stg} | storage temperature | | | -65 | 150 | °C |

- Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint. Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm².



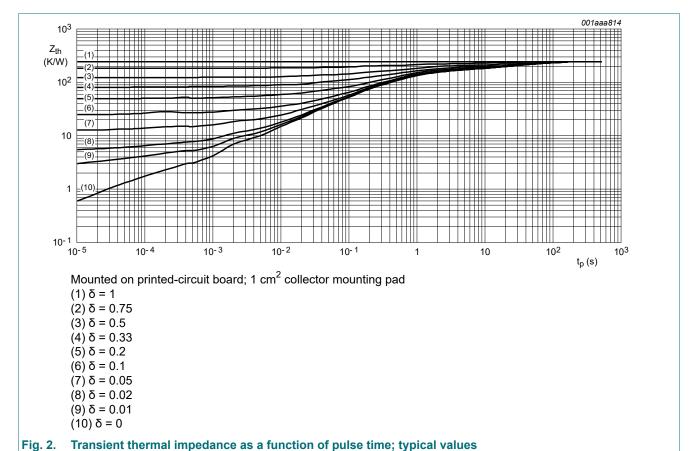
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9. Thermal characteristics

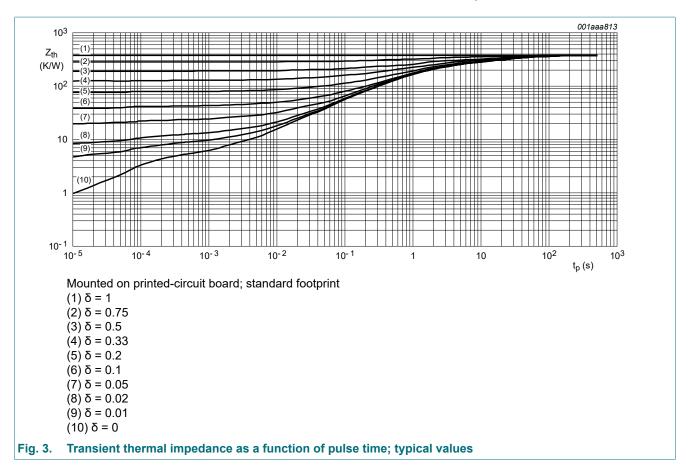
Table 6. Thermal characteristics

| Symbo | ol | Parameter | Conditions | | Min | Тур | Max | Unit |
|---------------|----|-------------------------|-------------|-----|-----|-----|-----|------|
| $R_{th(j-a)}$ | | thermal resistance from | in free air | [1] | - | - | 417 | K/W |
| | | junction to ambient | | [2] | - | - | 260 | K/W |

- 1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm².



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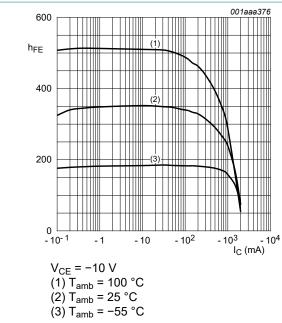
100 V, 1 A PNP low VCEsat transistor

10. Characteristics

Table 7. Characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|----------------------|---|---|------|-----|------|------|
| $V_{(BR)CBO}$ | collector-base breakdown voltage | $I_C = -100 \mu A; I_E = 0 A; T_{amb} = 25 °C$ | -120 | - | - | V |
| V _{(BR)CEO} | collector-emitter breakdown voltage | I_C = -10 mA; I_B = 0 A; T_{amb} = 25 °C | -100 | - | - | V |
| V _{(BR)EBO} | emitter-base breakdown voltage (collector open) | I _C = 0 A; T _{amb} = 25 °C | -5 | - | - | V |
| I _{CBO} | collector-base cut-off | V _{CB} = -80 V; I _E = 0 A; T _{amb} = 25 °C | - | - | -100 | nA |
| | current | V _{CB} = -80 V; I _E = 0 A; T _j = 150 °C | - | - | -50 | μΑ |
| I _{EBO} | emitter-base cut-off current | V _{EB} = -4 V; I _C = 0 A; T _{amb} = 25 °C | - | - | -100 | nA |
| I _{CES} | collector-emitter cut-off current | V _{CE} = -80 V; V _{BE} = 0 V; T _{amb} = 25 °C | - | - | -100 | nA |
| h _{FE} | DC current gain | V _{CE} = -5 V; I _C = -1 mA; T _{amb} = 25 °C | 150 | - | - | |
| | | V _{CE} = -5 V; I _C = -250 mA; T _{amb} = 25 °C | 150 | - | - | |
| | | V_{CE} = -5 V; I_{C} = -500 mA; pulsed; t_{p} ≤ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C | 150 | - | 450 | |
| | | V_{CE} = -5 V; I_{C} = -1 A; pulsed; t_{p} ≤ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C | 125 | - | - | |
| V _{CEsat} | collector-emitter | I _C = -250 mA; I _B = -25 mA; T _{amb} = 25 °C | - | - | -120 | mV |
| | saturation voltage | I _C = -500 mA; I _B = -50 mA; T _{amb} = 25 °C | - | - | -180 | mV |
| | | I_C = -1 A; I_B = -100 mA; pulsed; $t_p \le$ | - | - | -320 | mV |
| R _{CEsat} | collector-emitter saturation resistance | 300 μs; δ ≤ 0.02; T _{amb} = 25 °C | - | 170 | 320 | mΩ |
| V _{BEsat} | base-emitter saturation voltage | I _C = -1 A; I _B = -100 mA; T _{amb} = 25 °C | - | - | -1.1 | V |
| V_{BEon} | base-emitter turn-on voltage | V _{CE} = -5 V; I _C = -1 A; T _{amb} = 25 °C | - | - | -1 | V |
| f _T | transition frequency | V_{CE} = -10 V; I_{C} = -50 mA; f = 100 MHz; T_{amb} = 25 °C | 100 | - | - | MHz |
| C _c | collector capacitance | V _{CB} = -10 V; I _E = 0 A; i _e = 0 A; f = 1 MHz; T _{amb} = 25 °C | - | - | 17 | pF |

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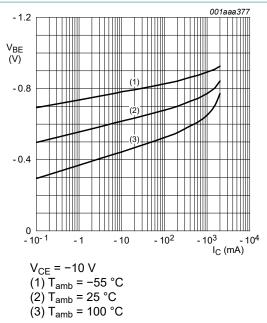


$$(1) T_{amb} = 100 °C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 4. DC current gain as a function of collector current; typical values

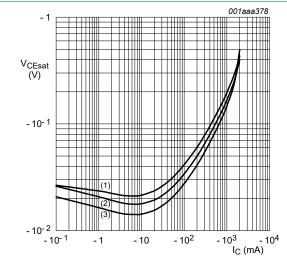


(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 100 \, ^{\circ}C$$

Fig. 5. Base-emitter voltage as a function of collector current; typical values



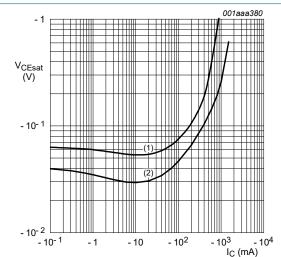
$$I_{\rm C}/I_{\rm B}=10$$

(1)
$$T_{amb} = 100 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 6. Collector-emitter saturation voltage as a function of collector current; typical values



$$T_{amb}$$
 = 25 °C

$$(1) I_{\rm C}/I_{\rm B} = 50$$

(2)
$$I_C/I_B = 20$$

Collector-emitter saturation voltage as a Fig. 7. function of collector current; typical values

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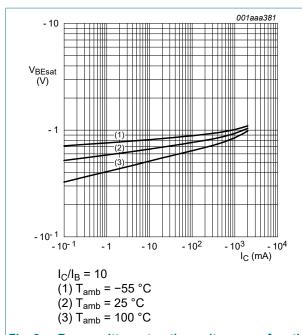


Fig. 8. Base-emitter saturation voltage as a function of collector current; typical values

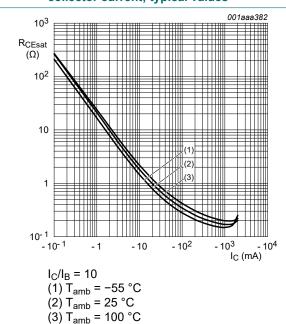


Fig. 10. Collector-emitter saturation resistance as a function of collector current; typical values

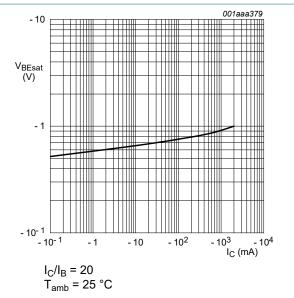
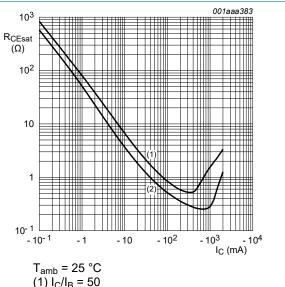


Fig. 9. Base-emitter saturation voltage as a function of collector current; typical values

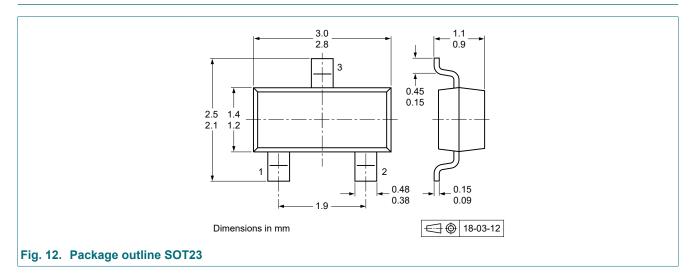


(1) $I_C/I_B = 50$ (2) $I_C/I_B = 20$

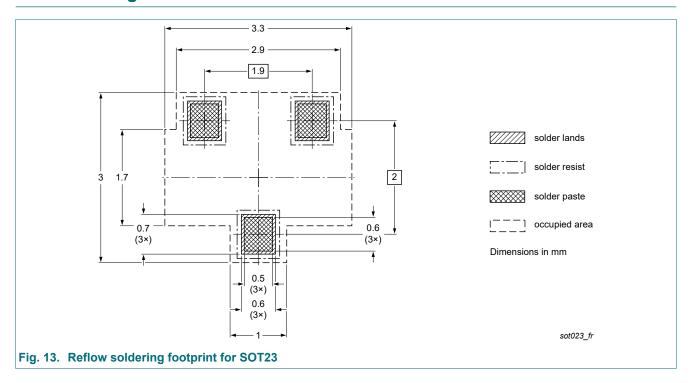
Fig. 11. Collector-emitter saturation resistance as a function of collector current; typical values

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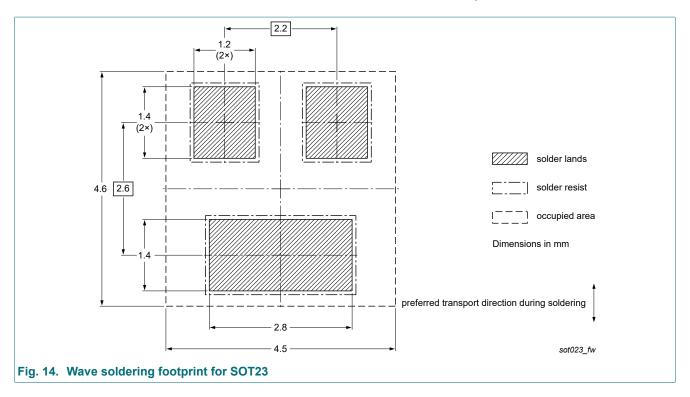
11. Package outline



12. Soldering



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13. Revision history

Table 8. Revision history

| Tubic o. Itevision mistory | | | | | | | |
|----------------------------|--------------|---|---------------|---------------|--|--|--|
| Data sheet ID | Release date | Data sheet status | Change notice | Supersedes | | | |
| PBSS9110T v.4 | 20230101 | Product data sheet | - | PBSS9110T v.3 | | | |
| Modifications: | I | Product changed to non-automotive qualification. Please refer to nexperia.com for automotive (-Q) product alternative(s). | | | | | |
| PBSS9110T v.3 | 20220523 | Product data sheet | - | PBSS9110T v.2 | | | |
| PBSS9110T v.2 | 20040513 | Product data sheet | - | PBSS9110T v.1 | | | |
| PBSS9110T v.1 | 20040506 | Product data sheet | - | - | | | |

Product data sheet

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14. Legal information

Data sheet status

| Document status [1][2] | Product status [3] | Definition |
|--------------------------------|-----------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
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| Product [short] data sheet | Production | This document contains the product specification. |

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- [2] The term 'short data sheet' is explained in section "Definitions".
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